

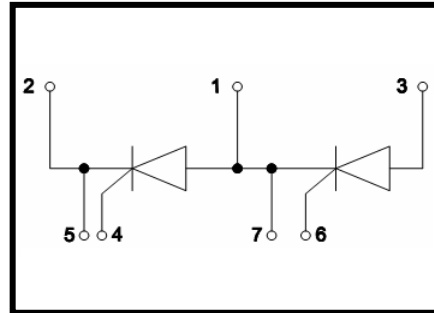
Features

- Isolation voltage 3000 V~
- Industrial Standard Package
- High Surge Capability
- Glass Passivated Chips
- Simple Mounting
- Electrically Isolated by DBC Ceramic



Applications

- DC Motor Control and Drives
- Battery Charges
- Welders
- Power Converters
- Lighting Control
- Heat and Temperature Control



Advantages

- Space and weight savings
- Improved temperature and power cycling

ABSOLUTE MAXIMUM RATINGS

 $T_C=25^{\circ}\text{C}$ unless otherwise specified

Symbol	Test Condition	Value	Unit
V_{RRM}/V_{DRM}		1600	V
$I_{T(AV)}$	$T_C=85^{\circ}\text{C}$, 180° conduction, half sine wave;	110	A
$I_{T(RMS)}$	as AC switch;	235	A
I_{TSM}	$T_J=45^{\circ}\text{C}$, $t=10\text{ms}$ (50Hz), sine, $V_R=0$;	2500	A
	$T_J=45^{\circ}\text{C}$, $t=8.3\text{ms}$ (60Hz), sine, $V_R=0$;	2700	
	$T_J=45^{\circ}\text{C}$, $t=10\text{ms}$ (50Hz), sine, $V_R=V_{RRM}$;	2200	
	$T_J=45^{\circ}\text{C}$, $t=8.3\text{ms}$ (60Hz), sine, $V_R=V_{RRM}$;	2400	
I^2t	$T_J=45^{\circ}\text{C}$, $t=10\text{ms}$ (50Hz), sine, $V_R=0$;	31	KA^2s
	$T_J=45^{\circ}\text{C}$, $t=8.3\text{ms}$ (60Hz), sine, $V_R=0$;	30	
	$T_J=45^{\circ}\text{C}$, $t=10\text{ms}$ (50Hz), sine, $V_R=V_{RRM}$;	24	
	$T_J=45^{\circ}\text{C}$, $t=8.3\text{ms}$ (60Hz), sine, $V_R=V_{RRM}$;	23.9	
I_{DRM}/I_{RRM}	$T_J=130^{\circ}\text{C}$, $V_D=V_R=1600\text{V}$, gate open circuit;	20	mA
dV/dt	$T_J=130^{\circ}\text{C}$, exponential to 67% rated V_{DRM}	500	V/us
V_{ISOL}	50Hz, all terminals shorted, $t=1\text{s}$, $I_{ISOL}\leq 1\text{mA}$;	3000	V~
T_J	Max. junction operating temperature range	-40~130	$^{\circ}\text{C}$
T_{STG}	Max. storage temperature range	-40~150	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS $T_C=25^{\circ}\text{C}$ unless otherwise specified

Symbol	Test Condition	Min.	Typ.	Max.	Unit
V_{TO}	$16.7\% \times p \times I_{AV} < I < p \times I_{AV}, T_J = 130^{\circ}\text{C};$			0.80	V
	$I > p \times I_{AV}, T_J = 130^{\circ}\text{C};$			0.85	V
r_t	$16.7\% \times p \times I_{AV} < I < p \times I_{AV}, T_J = 130^{\circ}\text{C};$			2.37	m Ω
	$I > p \times I_{AV}, T_J = 130^{\circ}\text{C};$			2.25	m Ω
I_H	$V_{AK} = 6\text{V}$, resistive load;			250	mA
I_L	Anode supply =6V, resistive load=1 Ω , gate pulse =10V, 100us;			400	mA
V_{TM}	$I_{TM}=345\text{A}$, $t_d=10\text{ ms}$, half sine			1.54	V
P_{GM}	$t_p \leq 5\text{ms}$, $T_J=125^{\circ}\text{C};$			12	W
$P_{GM(AV)}$	$f=50\text{Hz}$, $T_J = 125^{\circ}\text{C};$			3	W
I_{GM}	$t_p \leq 5\text{ms}$, $T_J = 125^{\circ}\text{C};$			3	A
$-V_{GT}$				10	V
V_{GT}	$V_A=6\text{V}$, $R_A=1\Omega$, $T_J = -40^{\circ}\text{C};$			4	V
	$V_A=6\text{V}$, $R_A=1\Omega$;			2.5	
	$V_A=6\text{V}$, $R_A=1\Omega$, $T_J=125^{\circ}\text{C};$			1.7	
I_{GT}	$V_A=6\text{V}$, $R_A=1\Omega$, $T_J = -40^{\circ}\text{C};$			270	mA
	$V_A=6\text{V}$, $R_A=1\Omega$;			150	
	$V_A=6\text{V}$, $R_A=1\Omega$, $T_J=125^{\circ}\text{C};$			80	
V_{GD}	$V_{AK}=V_{DRM}$, $T_J=125^{\circ}\text{C}$			0.25	V
I_{GD}				6	mA
di/dt	$T_J = 25^{\circ}\text{C}$, $V_D=0.67V_{DRM}$, $I_{TM} = 345\text{A}$, $I_g = 500\text{mA}$, $tr < 0.5\text{ }\mu\text{s}$, $tp > 6\text{ }\mu\text{s}$			150	A/us

THERMAL AND MECHANICAL CHARACTERISTICS $T_C=25^{\circ}\text{C}$ unless otherwise specified

Symbol	Test Condition	value	Unit
R_{thjc}	DC operation,per junction;	0.30	K/W
R_{THCS}	Mounting surface smooth,flat and greased,per junction	0.1	K/W
Md	Mounting torque(M5)	3 to 5	N·m
	Terminal connection torque(M5)		
Weight	Typical value	105	g

Characteristic curves

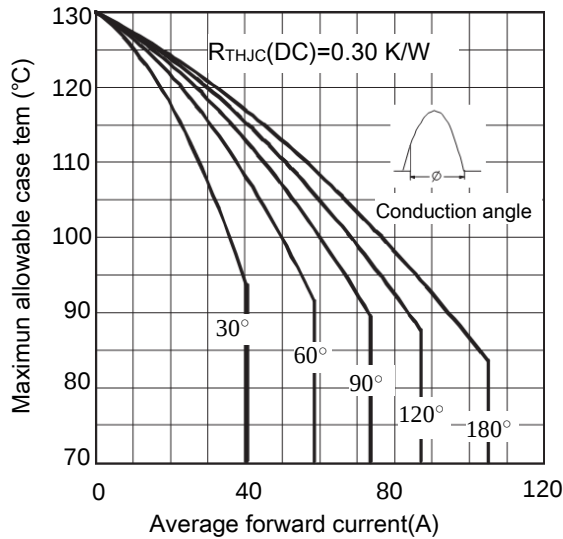


Figure 1. current rating characteristics

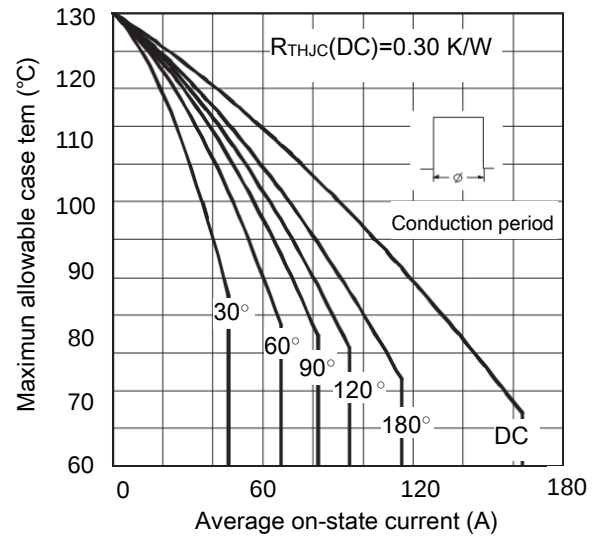


Figure 2. current rating characteristics

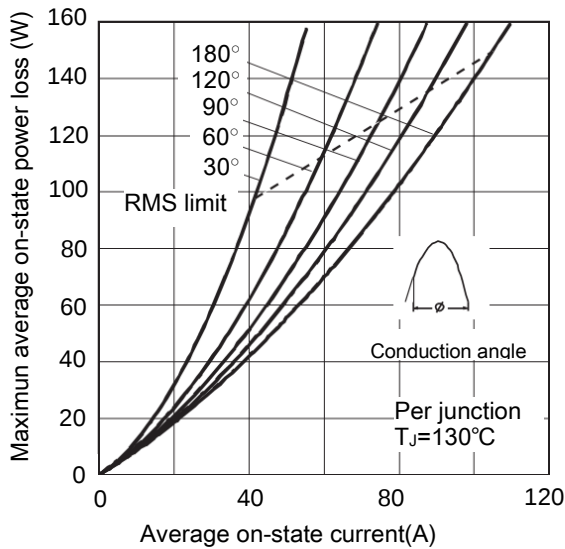


Figure 3. on-state power loss characteristics

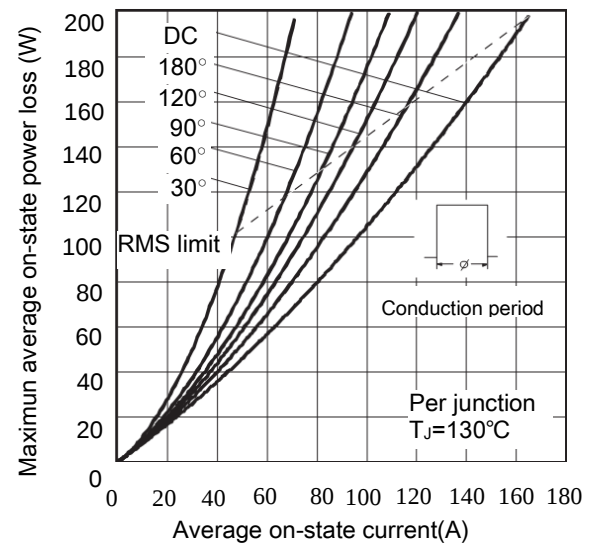


Figure 4. on-state power loss characteristics

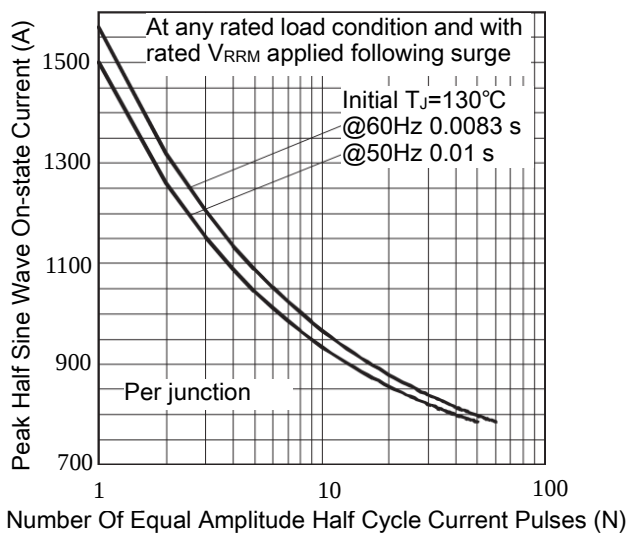


Figure 5. Maximum Non-Repetitive Surge Current

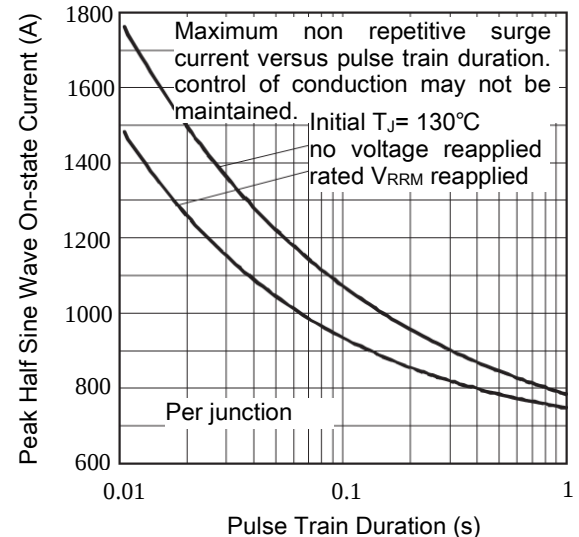


Figure 6. Maximum Non-Repetitive Surge Current

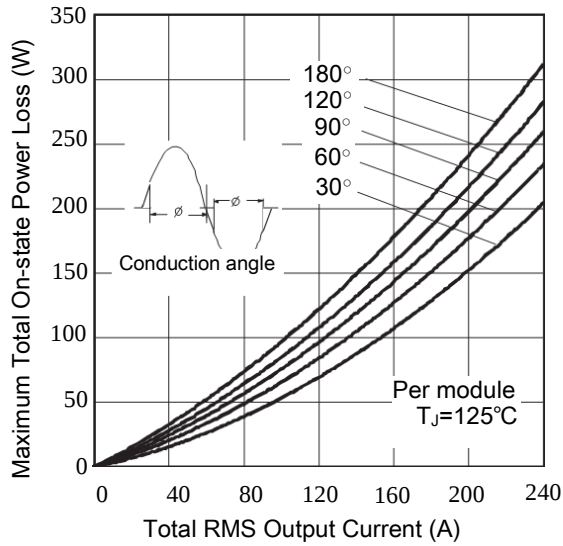


Figure 7. On-State Power Loss Characteristics-1

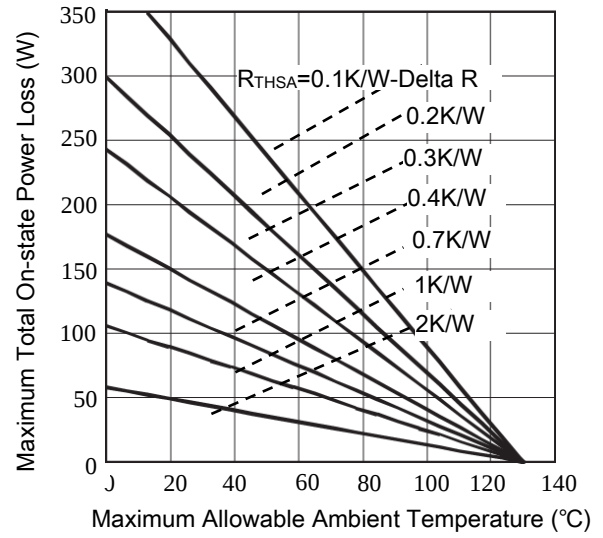


Figure.8 On-State Power Loss Characteristics-2

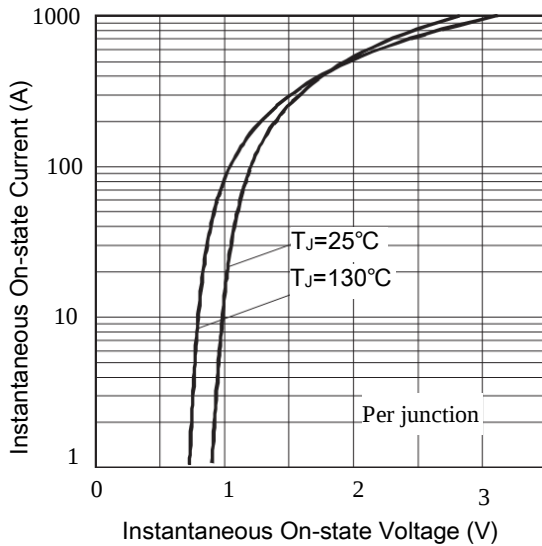


Figure.9 On State Voltage Drop Characteristics

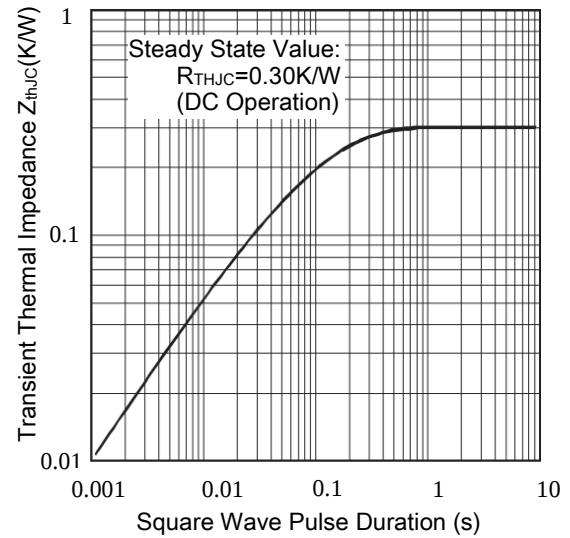


Figure.10 Thermal Impedance Z_{thJC} Characteristics

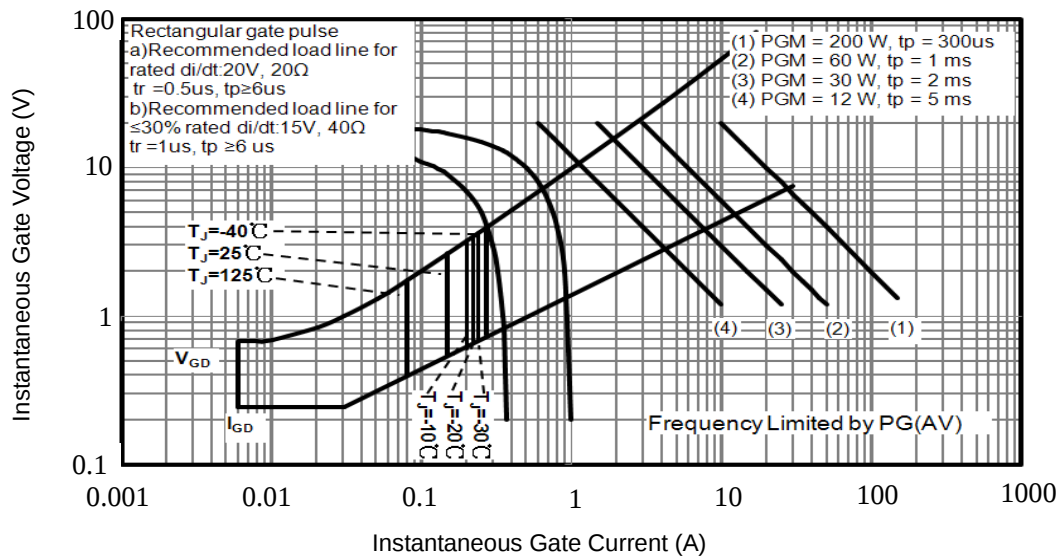


Figure.11 Gate Characteristics

Package Outline (Dimensions in mm)

